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Power electronics

Enabling sustainability and the green transition

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STMicroelectronics

Energy transition

Resources are a common asset...



Reduce greenhouse gas emission

- **Transport:** automotive, space & aeronautics
- **Industry:** pumps, motors, air-conditioning, multimodal energy approach
- **Digitalization:** massive data and « real time » calculation, data server, IA, ...

➔ « Fossil » energy to be massively reduced

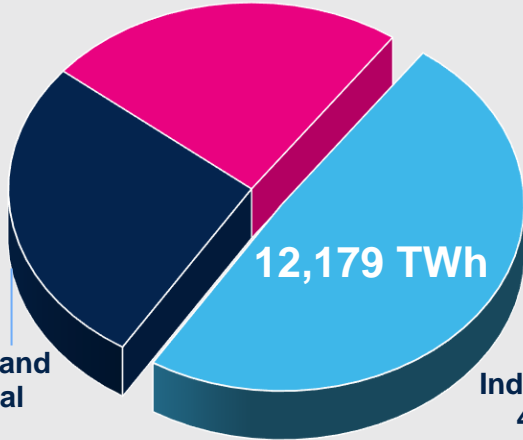
Optimize all usage

- **Electrical power is also scarce**
- From production to...
- Recycling & upcycling

The impact of global energy consumption

Electricity consumption by sector

Transportation
24%



24,856 TWh: total worldwide electricity consumption (2021)

1% efficiency improvement
in **industrial** electricity
consumption
=
121.79 TWh electricity
saved

By reducing our energy consumption,
we can reduce our carbon footprint

~18 standard
nuclear plants



66.08 MMBOe



13.85 M tce



3.7 billion

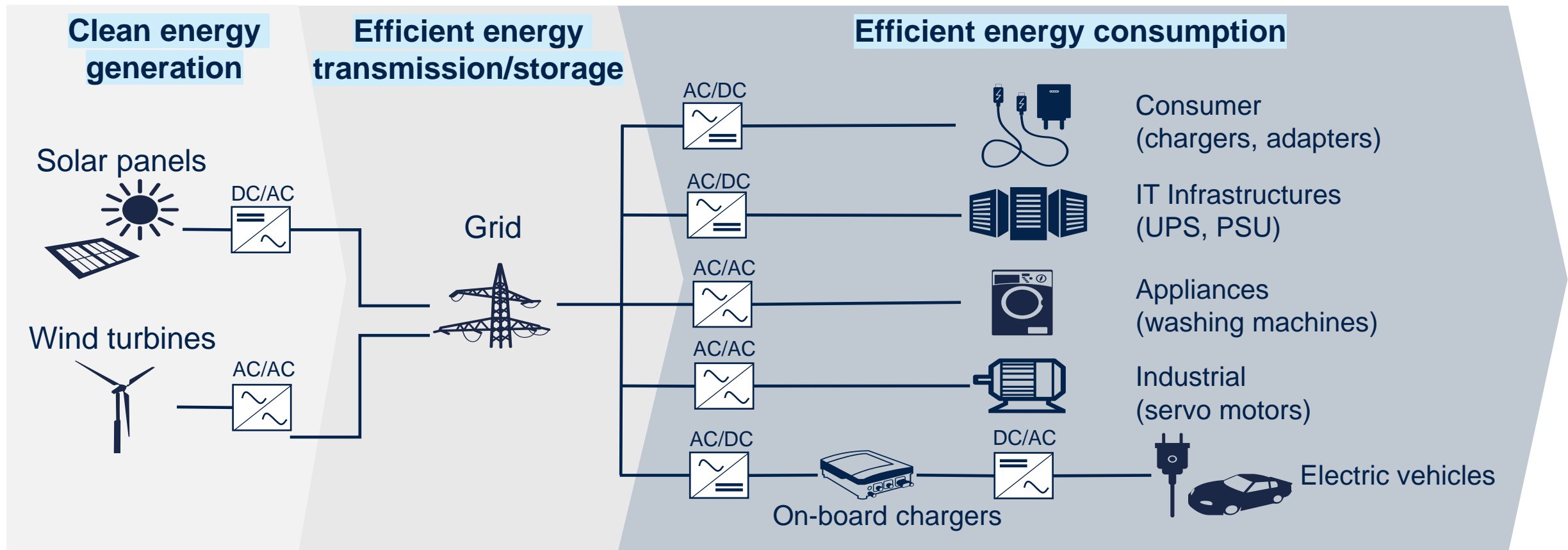


Can electronics drive sustainability?



Electricity: the future's key energy carrier

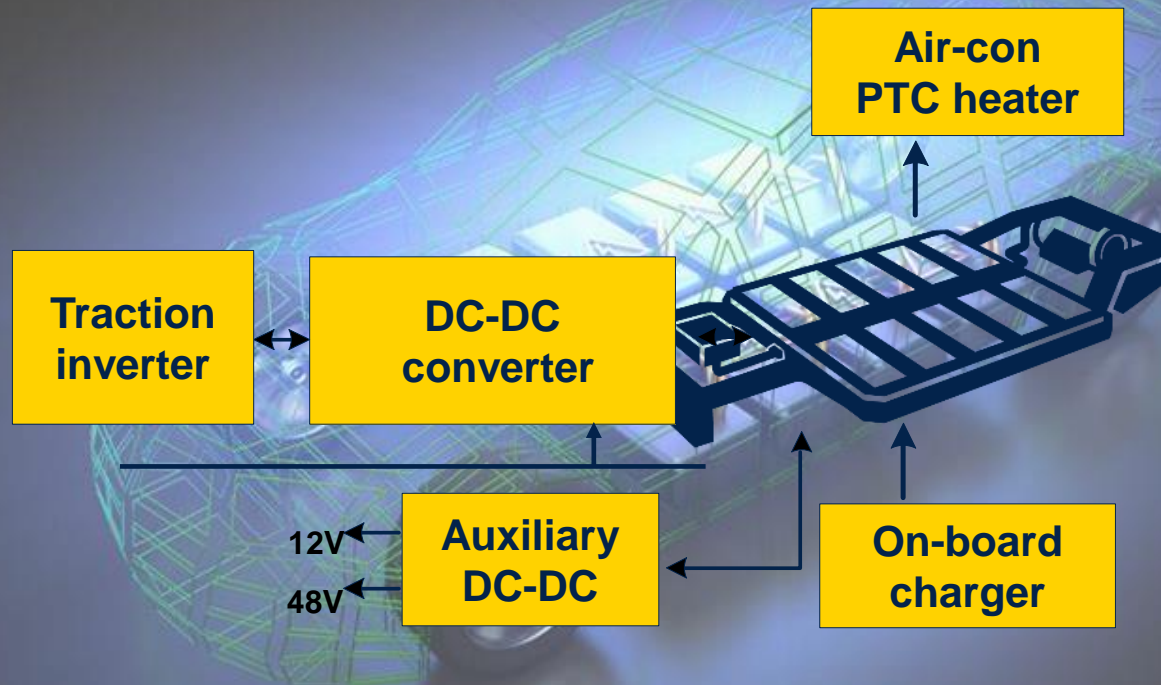
The critical role of power semiconductors in conversion, control, and processing



Contribution of electric vehicles to CO₂ reduction

Road transportation accounts for about 15% of CO₂ emissions globally

| Vehicle type | CO ₂ saving |
|------------------|------------------------|
| Full electric | 100% |
| Plug-in hybrid | 50-75% |
| Full hybrid | 20-30% |
| 48 V mild hybrid | 15-20% |



On-board chargers

SiC, GaN, & Si power MOSFETs, IGBT
Power modules
Rectifiers, fast diodes
Galvanic isolated drivers

DC-DC converter

SiC, GaN, & Si power MOSFETs, IGBT
Power modul
MCU for power conversion
Galvanic isolated drivers

Traction inverter

SiC MOSFET and IGBT
Power modules
Rectifiers, galvanic isolated drivers

48 V system

Smart half-bridges
48 V high-side drivers
Silicon power MOSFETs

Where is STMicroelectronics in a EV car

More than 3100 electronic components by ST



Comfort

More than 1000

- Seat adjustment
- sunroof
- lifting tailgate system

Safety

More than 1000

- Air-bag & ABS
- BodyGuard collision ADAS

Audio/navigation

More than 500

- Telematics and Navigation
- Infotainment
- Digital Cluster

Electrification

More than 600

- Charging
- Traction
- Battery management system

Home & building energy savings

Residential & commercial lighting, HVAC, and appliances use >50% of total electricity consumption



>40%
Energy Saving

Washing machine
From Class D to Class A++



>30%
Energy Saving

Air conditioning
From analog to digital
From AC to BLDC control



>70%
Energy Saving

Digital consumer power supply
Efficiency > 98% in run mode
Stand-by power < 1mW



>80%
Energy Saving

Electronic lighting
From incandescent bulbs
to LED lighting

Power management

Power Factor Corrector
Power Converter ICs
LED Drivers

Power switches & drivers

Power MOSFETs, IGBT
Power Modules and IPM
Driver ICs

Sensors & control unit

Microcontrollers
Motion and environmental sensors

Motor control

Microcontrollers
Application Specific Standard Products
System in Package



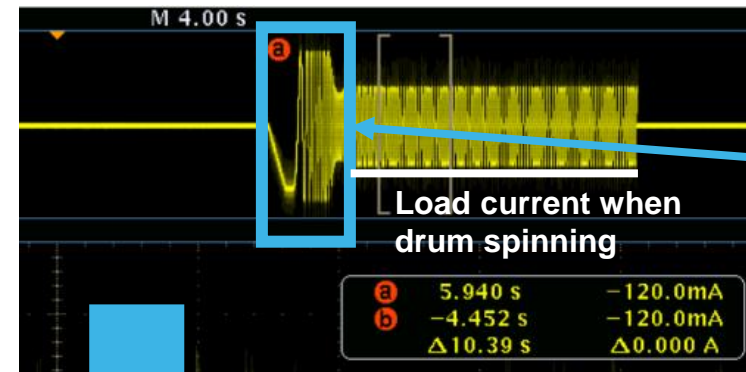
Adding intelligence to save energy & resources

Combination of **Edge AI clothes weighing** and **advanced Motor control algorithms** reduce the amount of water and detergent used and significantly lowers start up current

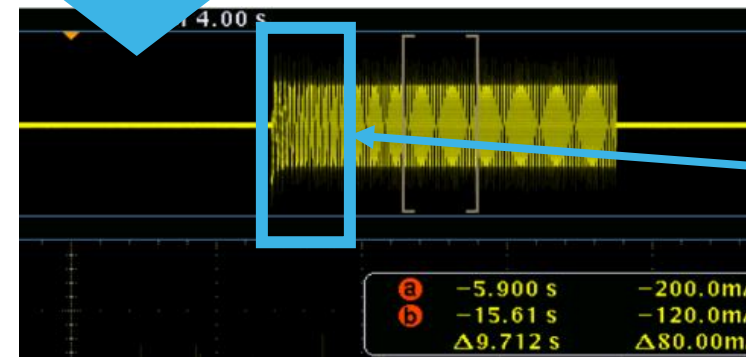


Energy saving
per washing cycle
~15-40%

Standard (open loop) sensorless startup



High peak current



Zero Speed Full Torque (ZeST) sensorless start-up

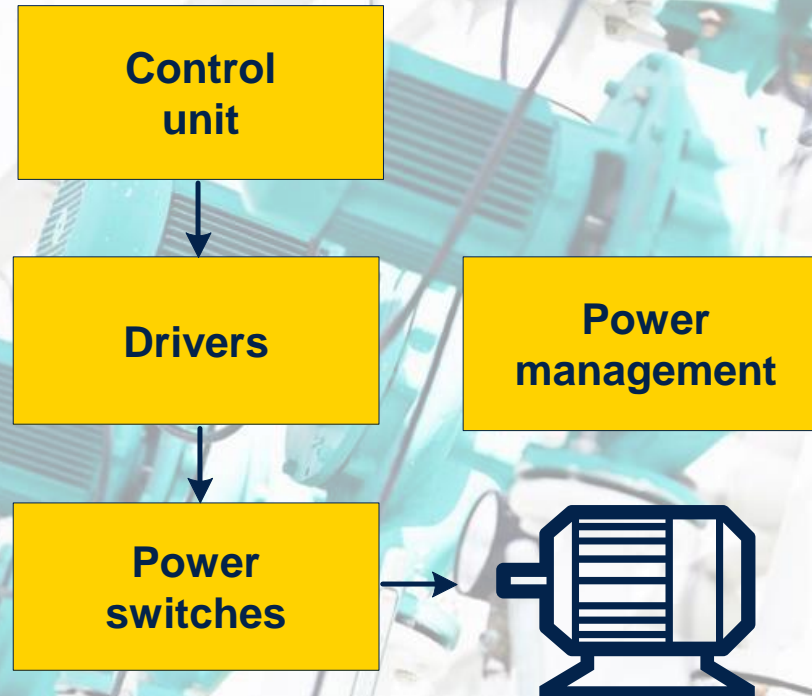
Potential energy savings with electric motors

Nearly 70 percent of all industrial electrical energy is used to power electric motors

Variable speed drives (VSD) can reduce electric motor energy consumption by up to 50%.

Only ~12% of motors globally are equipped with VSD

Efficiency, size, power density, and overall system cost can be improved using WBG*-based VSD



Power switches

WBG MOSFETs
IGBT, IPM, Power Modules and Silicon Power MOSFETs

Drivers

Gate Driver ICs

Control unit

Microcontrollers
Application Specific Standard Products
System in Package

Power management

Power converter ICs
Rectifiers, Thyristors
Silicon Power MOSFETs and IGBT

Solar power generation

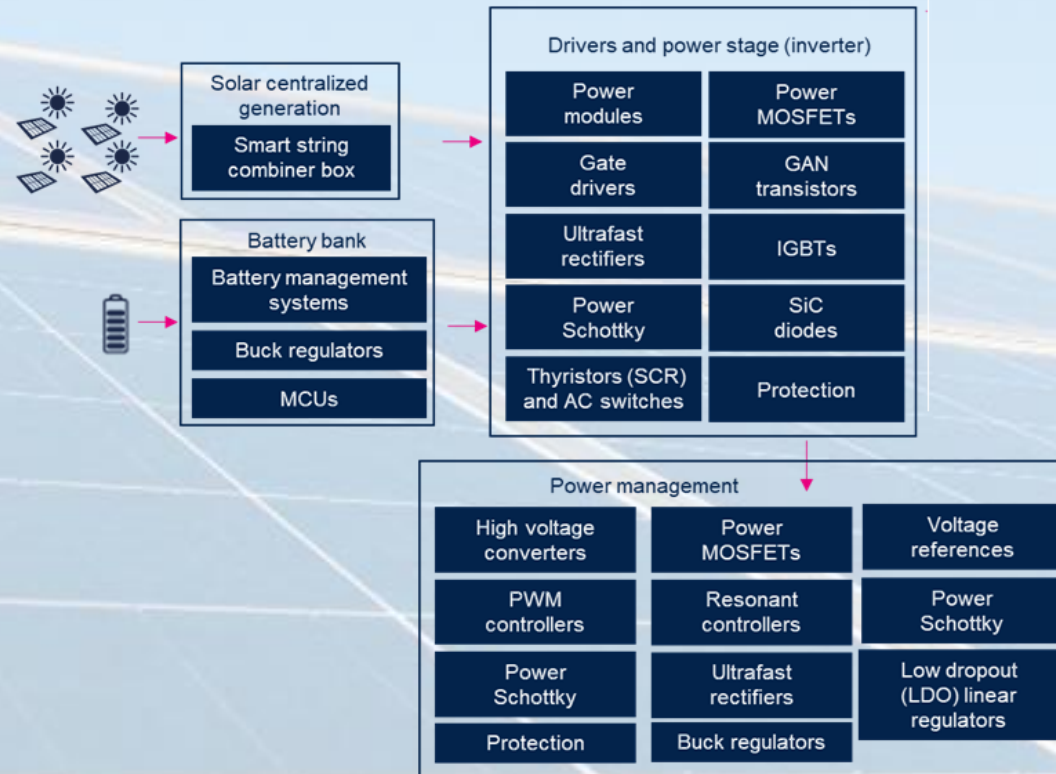
Solar panels can generate, store, & share electricity thanks to semiconductors

3.6%
solar PV power
In 2021
**Of global electricity
generation**

22%
growth vs 2021
**In global solar PV
power generation**

38%
from China
**PV power
generation growth**

7x
PV production
**Increase required
by 2030 vs 2021 for
Net Zero Scenario**



Key components

Inverter

SiC, GaN, & Si power MOSFETs, IGBT
Power modules
Rectifiers, fast diodes
Galvanic isolated drivers

Power management

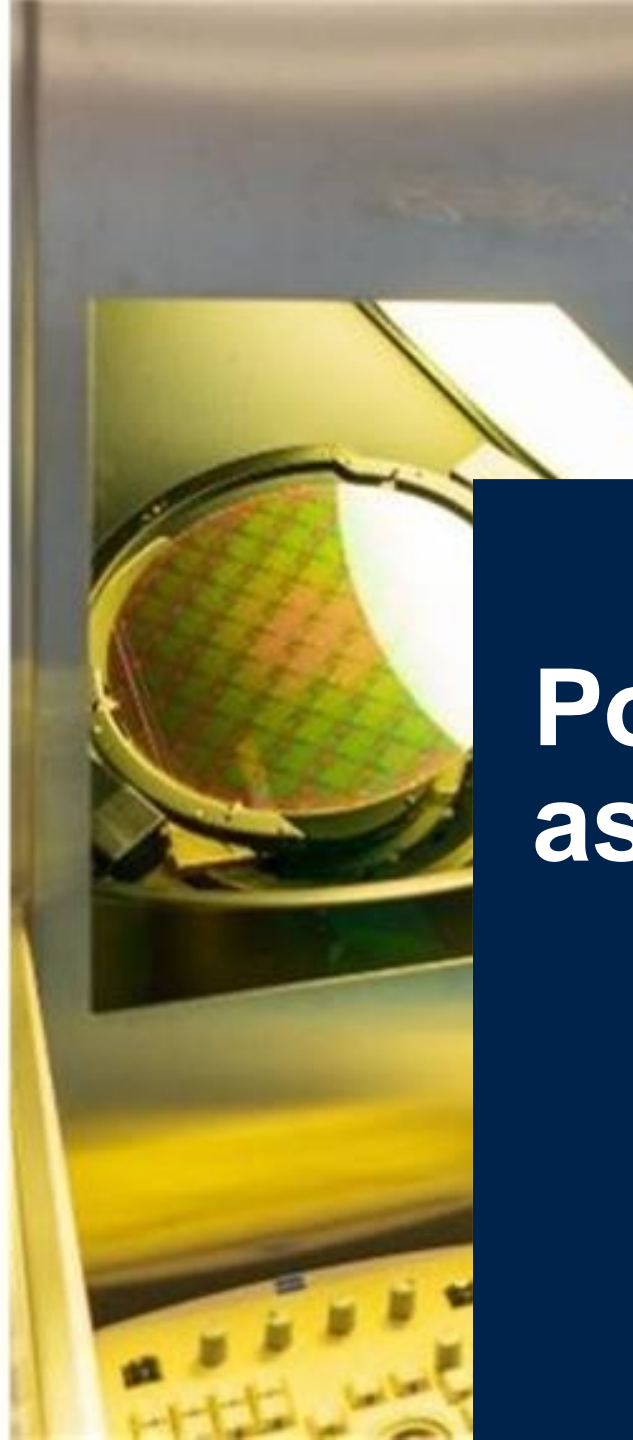
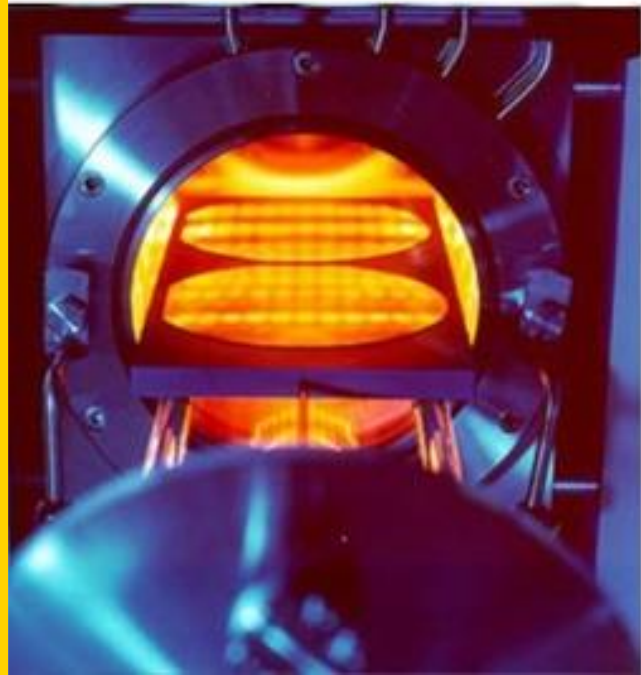
SiC, GaN, & Si power MOSFETs
Power modules
Rectifiers
PWM controllers
Galvanic isolated drivers

Battery management

Battery management ICs
Microcontrollers
Regulators

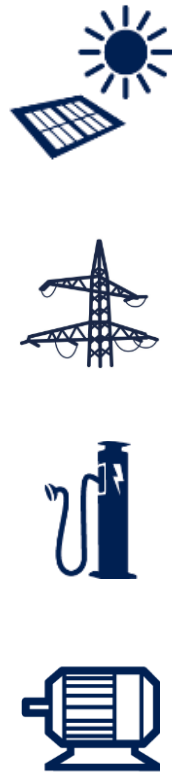


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Power semiconductors as key enablers

ST strategy in power electronics



...address

Green energy generation

Energy distribution

Energy storage

Electrification



...with ST innovation

Efficiency / Standby

- Optimization of existing silicon
- WBG technologies (SiC & GaN)
- Smart controllers

Power Density & integration

- Embedded galvanic isolation
- System in package (SiP)
- Innovative packages

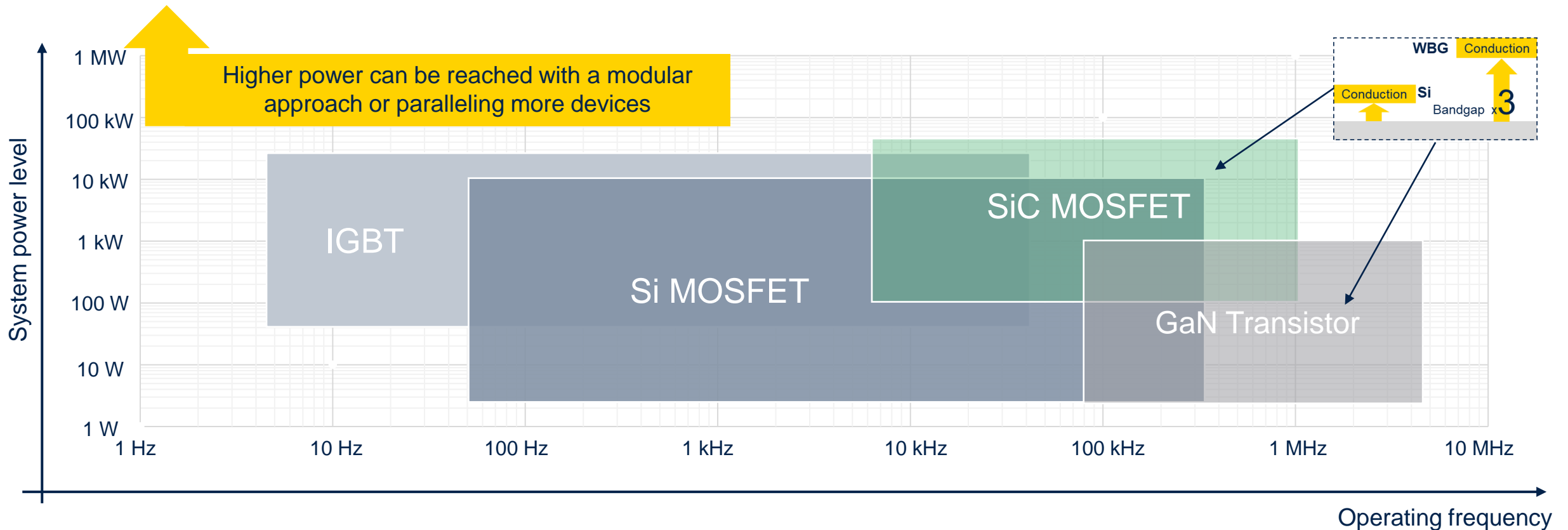
Flexibility & advanced features

- Digital power controller

Efficient solutions enabled by highly efficient semiconductors

Si, SiC, and GaN mapping

Silicon and wide bandgap materials are complementary



Advanced packaging discrete and module solution

Leadless package

Permeation of leadless package enablers for miniaturization



PowerFLAT



TO-LL

Leaded package

Standard packages that benefit from economy of scale



SOT223-2L DPAK



TO247-4L



H2PAK-7L



Top-side cooling SMD package

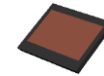
SMD packages that allow direct connection to heatsink



LFAK 12x12
TSC



HU3PAK



DirectGaN DSC
PEP

Multi-sintering package

High reliability, high power density, sintering on heat sink



STPAK

Modular package

Multi-purpose configurations, high power, top-side cooling



ACEPACK SMIT

Bare Dice

For high-temperature or customer in-house assemblies

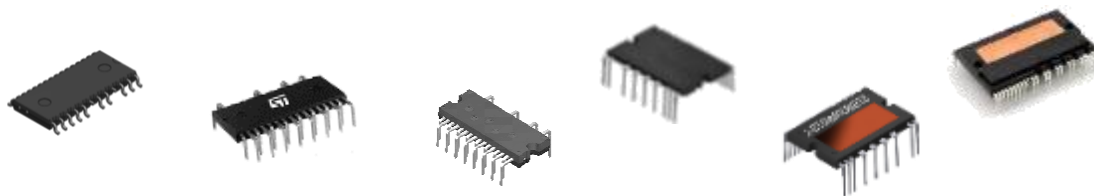


Tested cut/uncut wafer

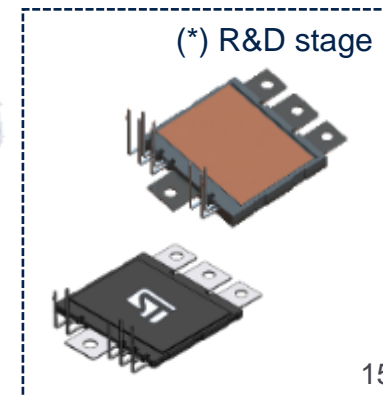
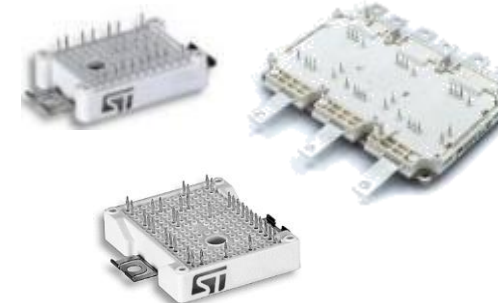


Tested dice in T&R

SLLIMM Intelligent Power Module



ACEPACK Power Module



Not complete list – just overview

Benefits of SiC technology

Key advantages of SiC for automotive



Traction inverter, on-board charger & DC-DC

and related infrastructure



Charging station

Longer driving range

> 600 km with SiC

Faster charging

SiC charging station handles 2x the energy

Car weight reduction

1% saving in the overall weight and space of an EV

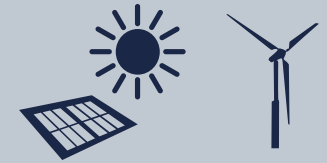
Key advantages of SiC for industrial



Factory automation



Power supply for servers



Renewable energy

Increased power efficiency

50% lower losses and with 5x frequency

Reduced total cost of ownership

Reduction of 20%

Smaller, more compact machines

Size/weight by 70%/80% with an average 50% reduction

Benefits of GaN technology

Fast charging tablets and notebooks



4x smaller



3x lighter

Power supplies for telecom and data centers/AI servers

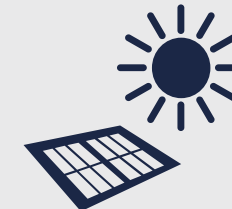


↑50% power density



↓20% power losses

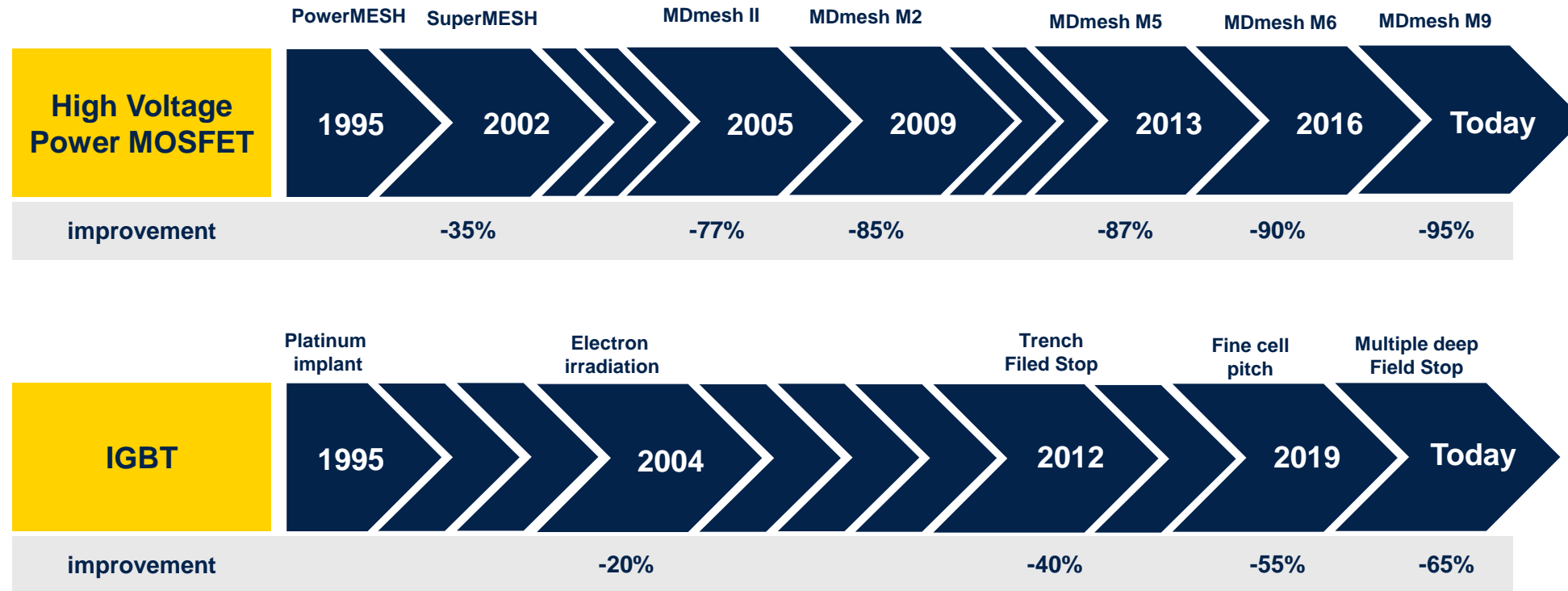
Solar ESS (energy storage system)



2x smaller

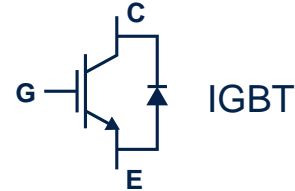
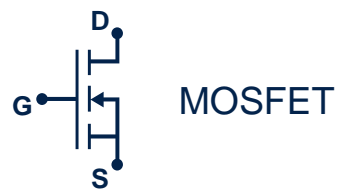
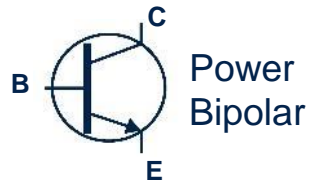
3x lighter

Silicon technology continues its march



Power Transistor Overview by technologies and applications

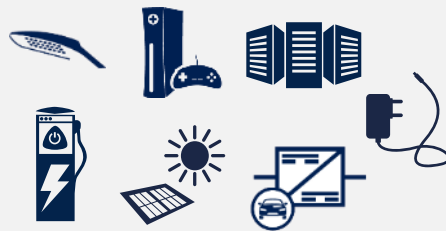
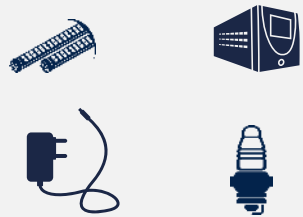
Silicon-based transistors



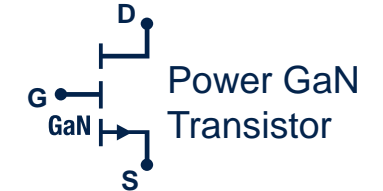
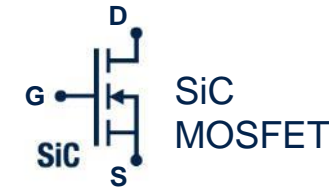
The bipolar Junction Transistor (BJT) is a 3-terminal, current-controlled electronic device that amplifies the current injected into the base B. In a bipolar junction transistor, electric current is conducted by both free electrons and holes.

MOSFET stands for metal-oxide-semiconductor field-effect transistor. The silicon-based MOSFET is a vertical, 3-terminal device with gate, drain and source terminals. Current conduction between drain and source is controlled by a voltage applied to the gate terminal G.

Insulated gate bipolar transistor is something of a cross between a conventional BJT and a vertical MOSFET. It has the output switching and conduction characteristics of a bipolar transistor but is voltage-controlled like a conventional MOSFET.

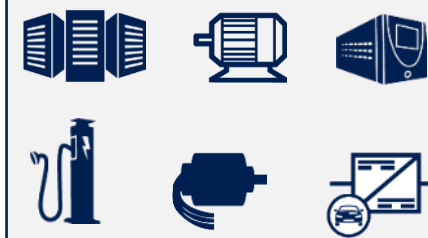


WBG-based transistors



SiC MOSFET is a wide bandgap material offering excellent static, dynamic and thermal performances. SiC-based MOSFETs are more tolerant to high temperatures and can be operated at higher voltages and higher switching frequencies.

Power GaN Transistors are High Electron Mobility lateral Transistors (HEMT) based on gallium nitride (GaN), a new wide bandgap material. They deliver major gains in terms of efficiency and power density involving high frequency-operation and low on-state resistance.

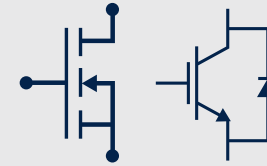


ST product portfolio enabling strategic trends



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Silicon devices



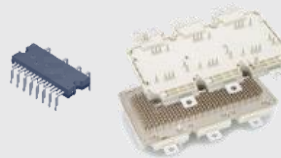
High-voltage MOSFETs
IGBTs, Power RF (LDMOS, DMOS)

Wide-bandgap (WBG) devices



SiC MOSFETs
Power & RF GaN

Modules



Intelligent Power Modules (IPM)
High Power Modules

Our technology starts with You



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